

11th International Summer School on RF MEMS and RF Microsystems IHP, Frankfurt (Oder) – Germany June 22nd – 26th 2015

Basics of mm-wave Measurements

Dr. Andrej Rumiantsev

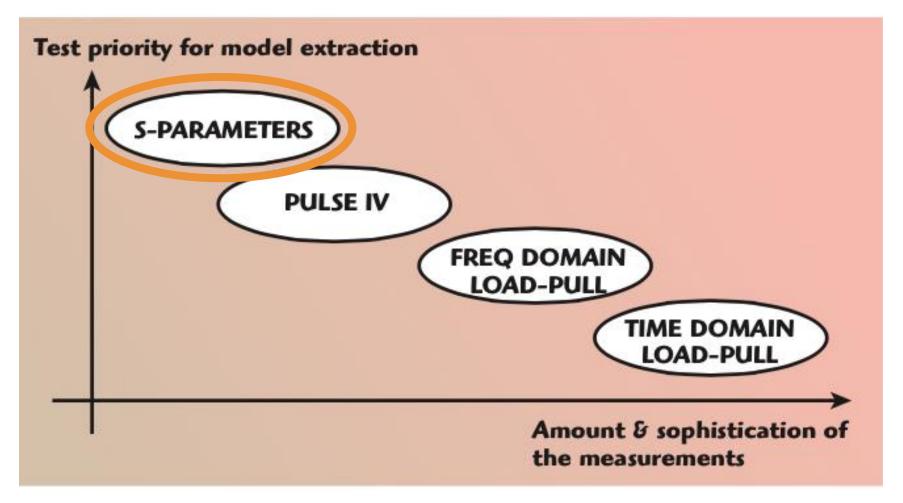
Director RF Technologies MPI Corporation



Outline

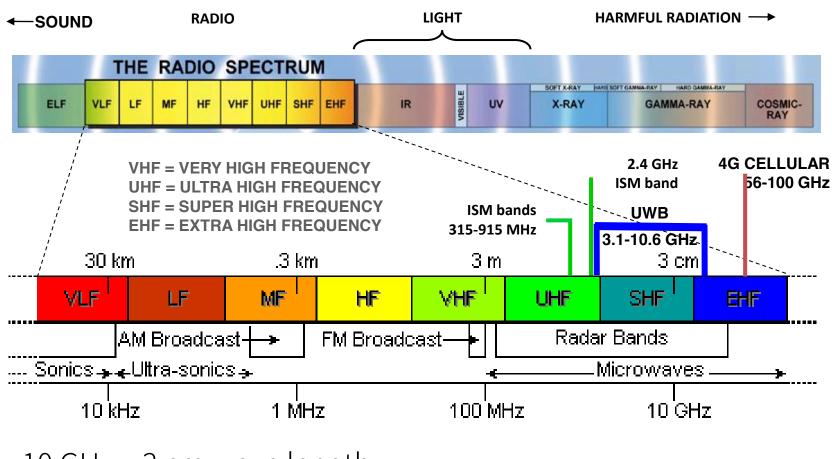
- Introduction
- S-parameters Basics
- Measurement of S-parameters
- VNA Building Blocks
- Instrumentation

Importance of RF-Measurements



T. Gasseling , MW Journal, 03-2012

Where Do RF & Microwaves Start?



10 GHz ~ 3 cm wave length

Source: JSC.MIL



Outline

- Introduction
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.. its all about Waves

Incident wave

a

Reflected wave

Transmitted wave

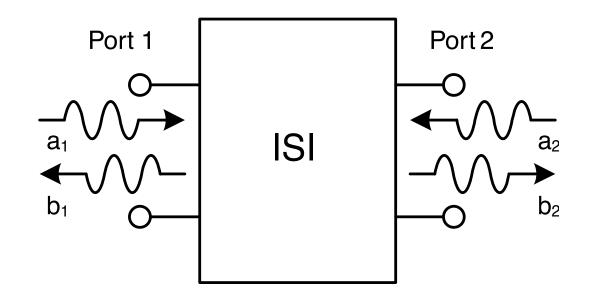
 b_{2}

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··· over S-Parameters

- Relationship of:
 - incident (a) and reflected/transmitted (b) waves at device terminals





Why S-Parameters

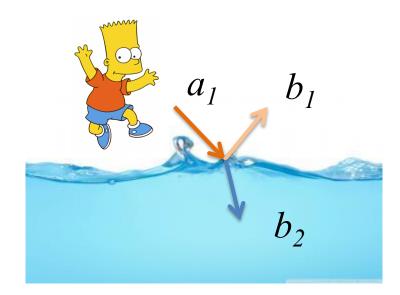
- Wave quantities are easy to measure
- Can be converted to Z-, Y-, H- and other parameters

$$S_{ii} = \frac{b_i}{a_i} = \frac{Z_{DUT} - Z_{REF}}{Z_{DUT} + Z_{REF}}$$

S-Parameter Matrix

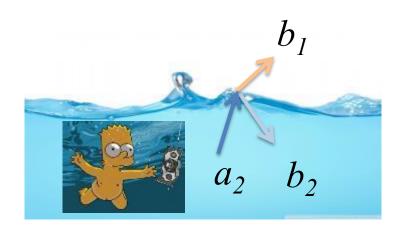
• Forward direction

$$S_{11}=b_1/a_1$$
 $S_{21}=b_2/a_1$



Reverse direction

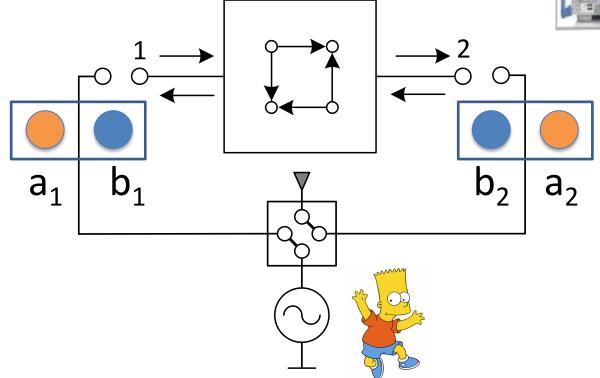
$$S_{22}=b_2/a_2$$
 $S_{12}=b_1/a_2$



S-Parameters Measured by VNA

• Vector Network Analyzer (VNA)



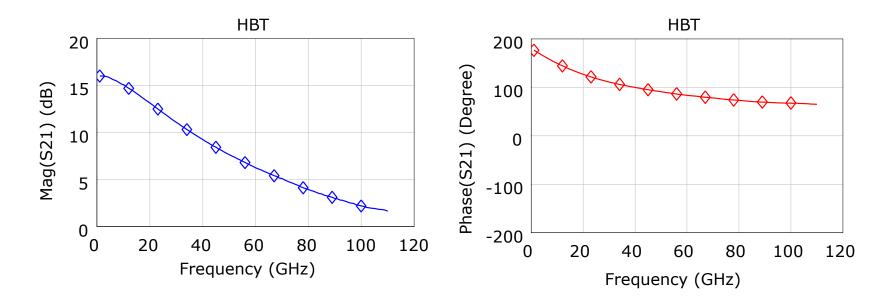


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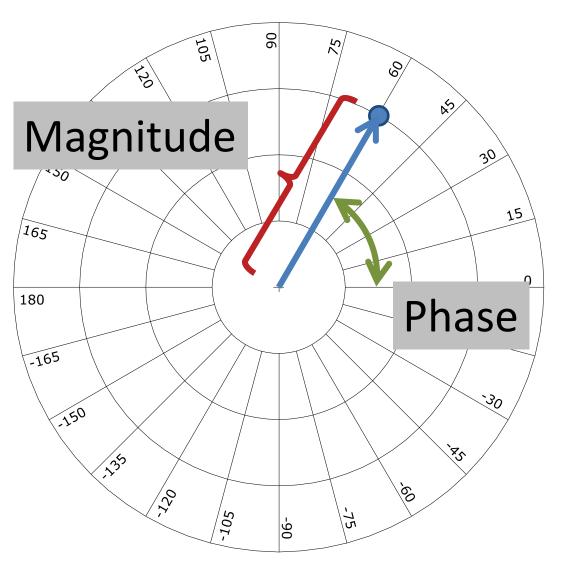
ИР

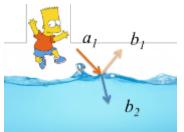
Why "Vector" ?

S-parameters are complex quantities:
 – Magnitude
 – Phase

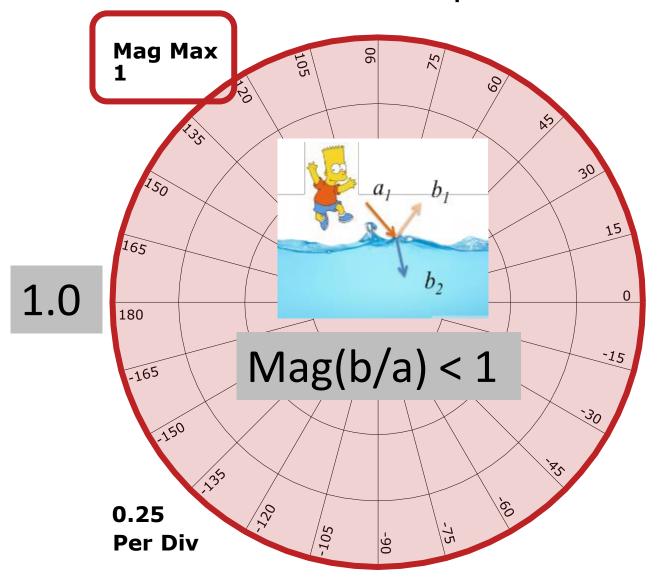


Vector on Polar Plot

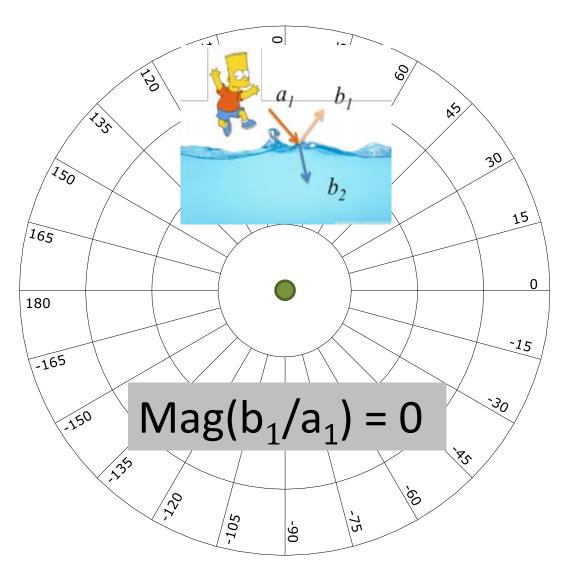




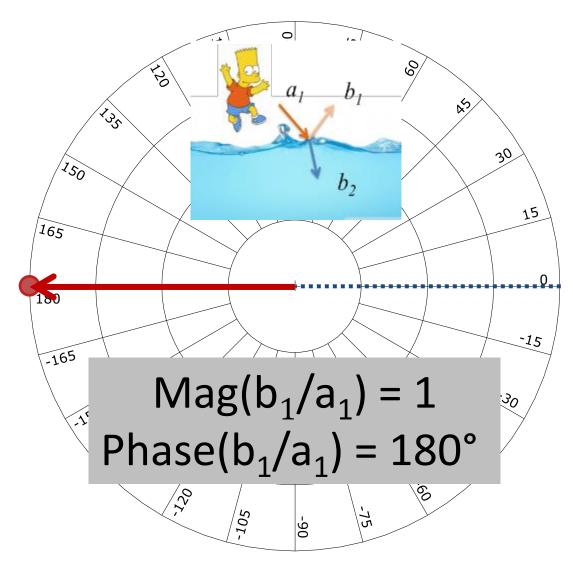
Passive Component



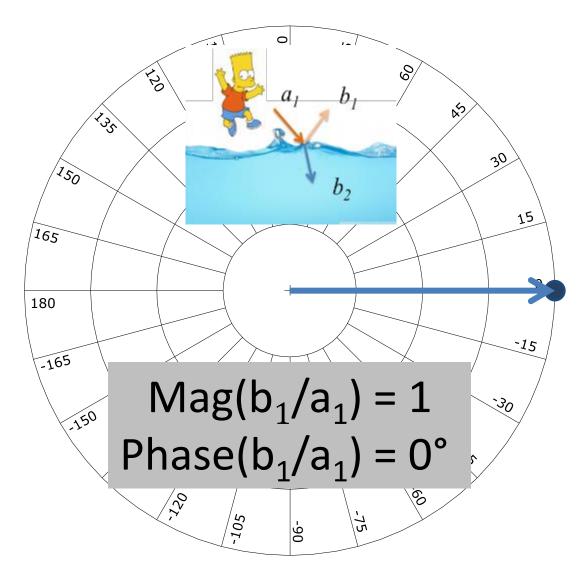
Match (Load)



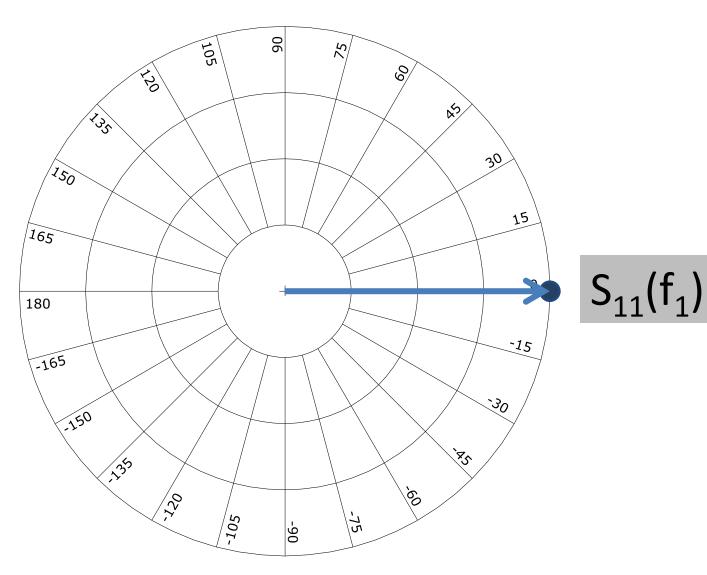
Short



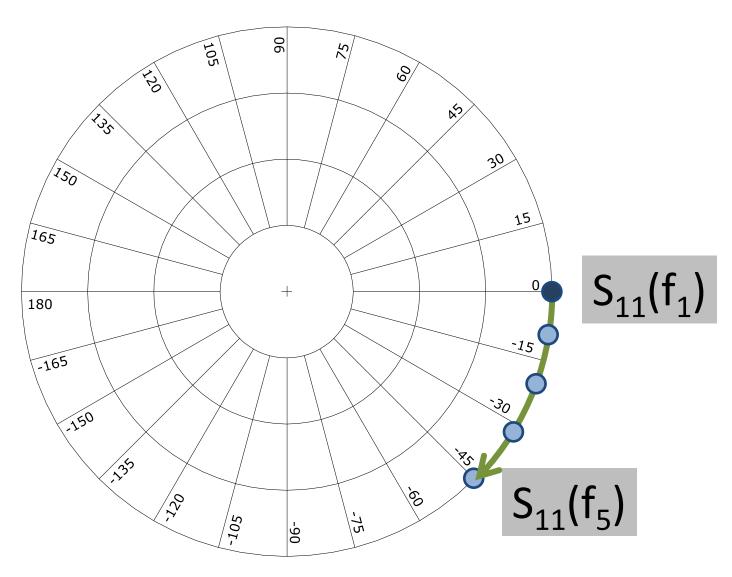
Open



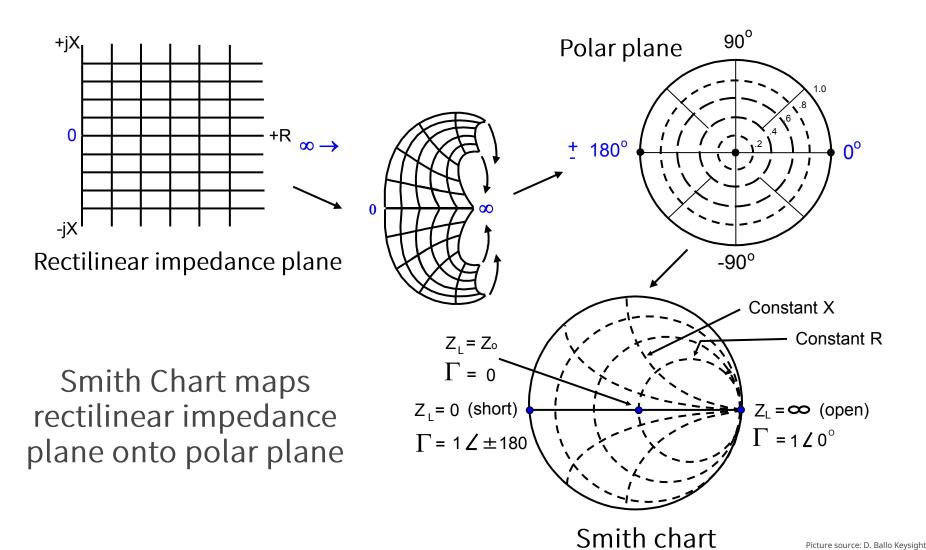
Data over Frequency



Data over Frequency

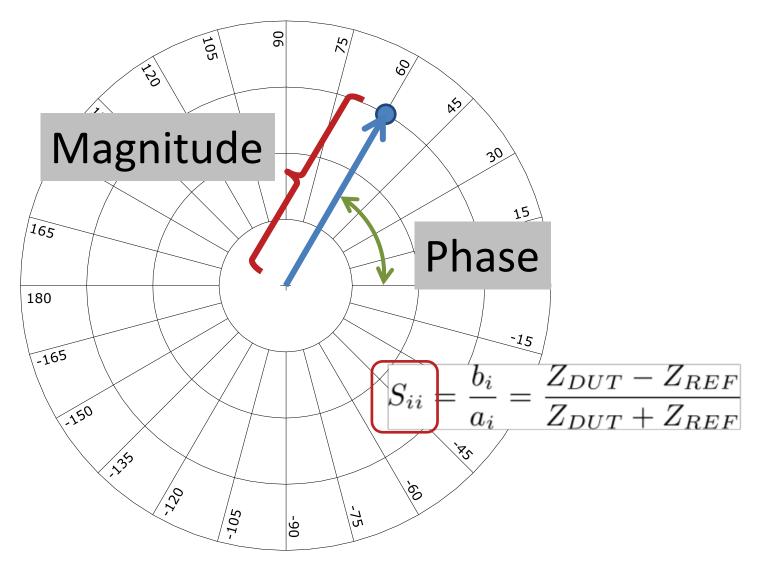


Smith Chart

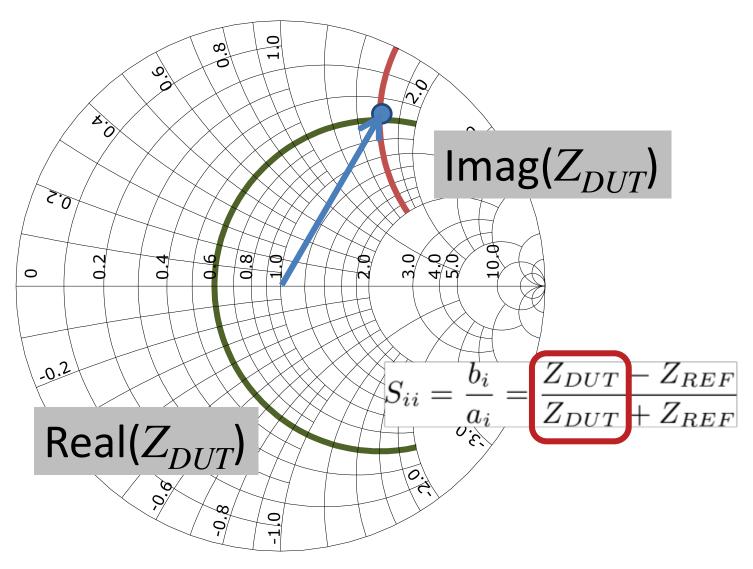


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Polar Chart vs. Smith Chart

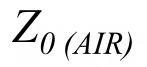


Polar Chart vs. Smith Chart





Matching of two Media = Transparency







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Matching of two Media = Transparency

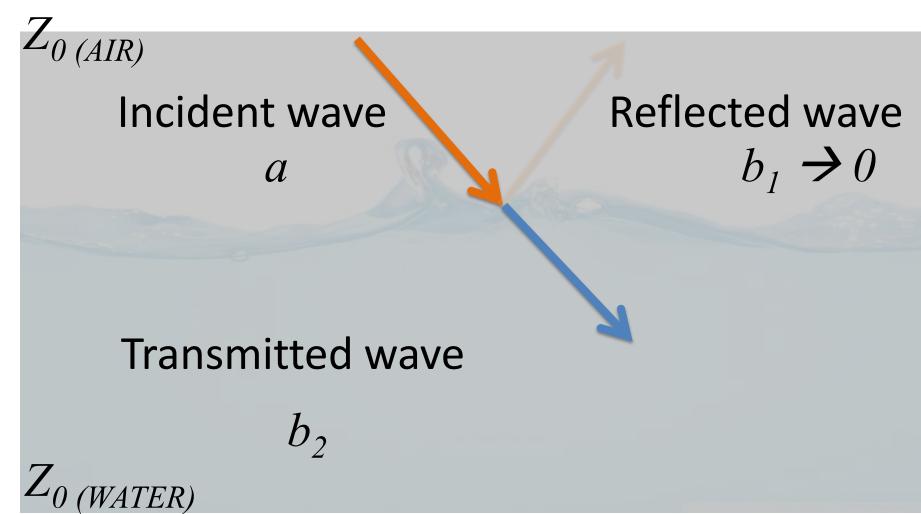




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Matching of two Media = Transparency



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Matching Conditions

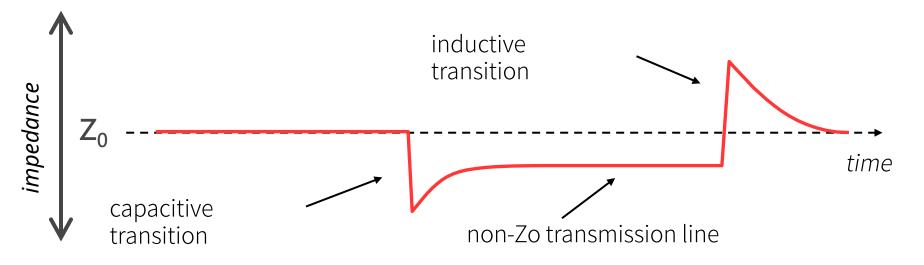
 $\frac{b_i}{a_i} = \frac{Z_{DUT} - Z_{REF}}{Z_{DUT} + Z_{REF}}$

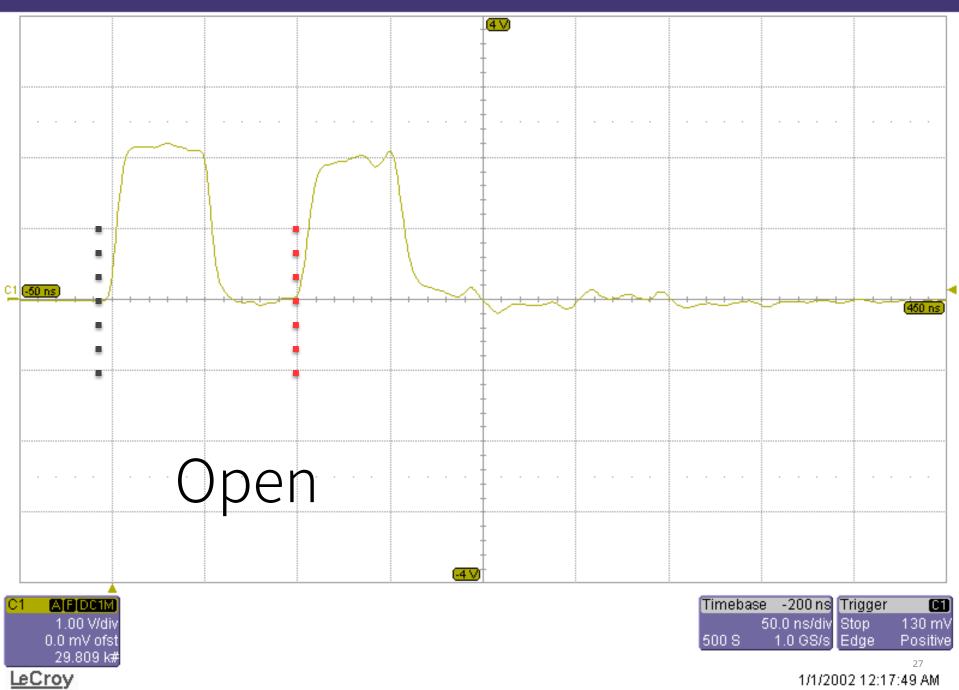
 $Z_{DUT} = Z_{REF}$ $S_{ii} \rightarrow 0$ $b_1 \rightarrow 0$

 $Z_{REF} = 50 \ \Omega$

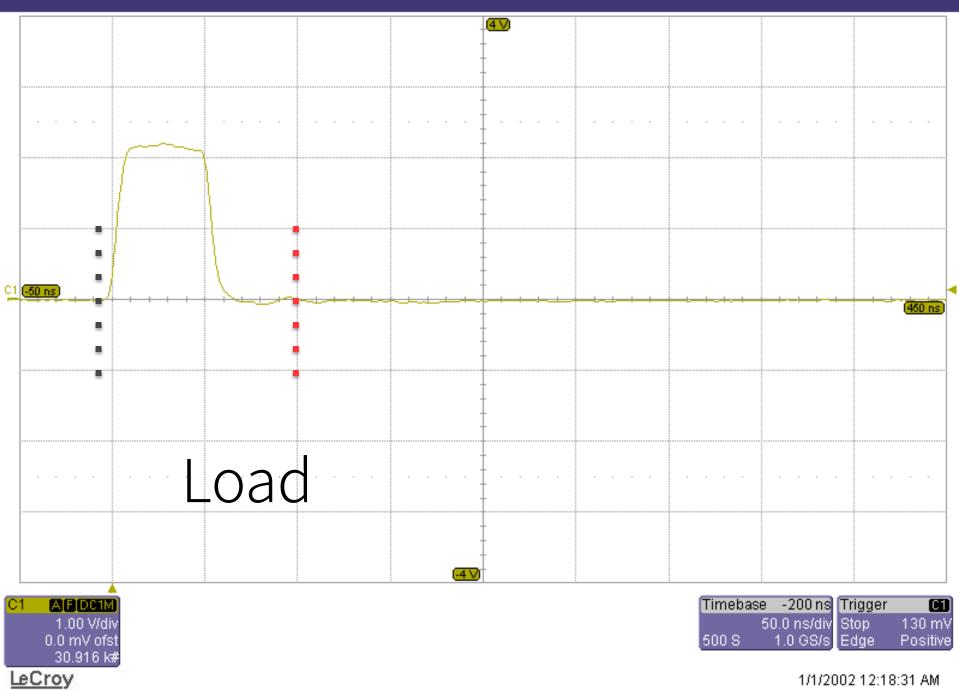
Time-Domain Reflectometry (TDR)

- Analyze impedance versus time
- Distinguish between inductive and capacitive transitions











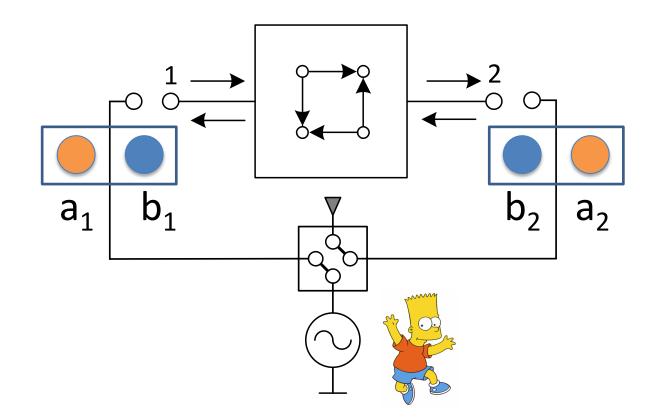
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Vector Network Analyzer

Device Under Test (DUT)



At the early days…



- Dr. Rohde and Dr. Schwarz first commercial product for RF measurement: 1933
- Z-g Graph from Rohde & Schwarz, early 50s



End of 60s…70s…80s…





HP 8410

Wiltron 310



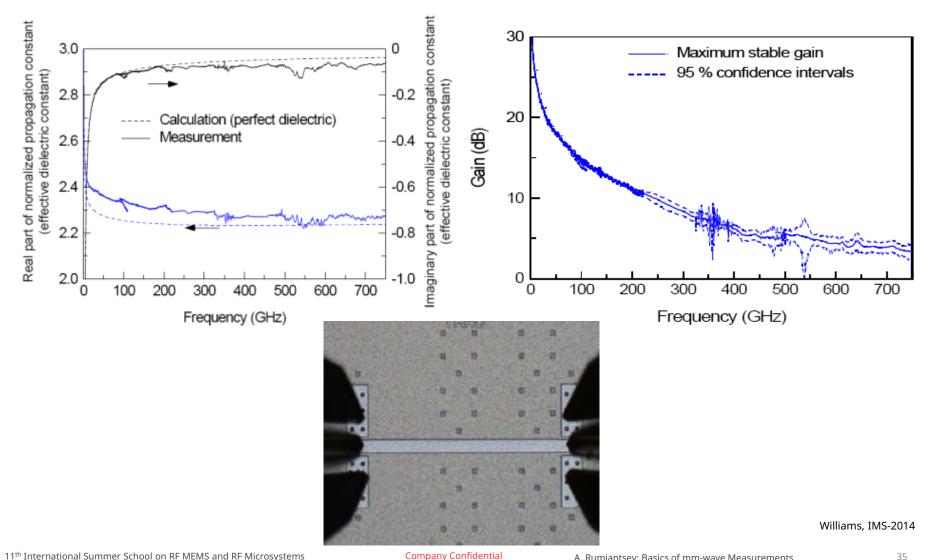
R&S



HP8410 Still Alive!



Today: On-Wafer Measurement



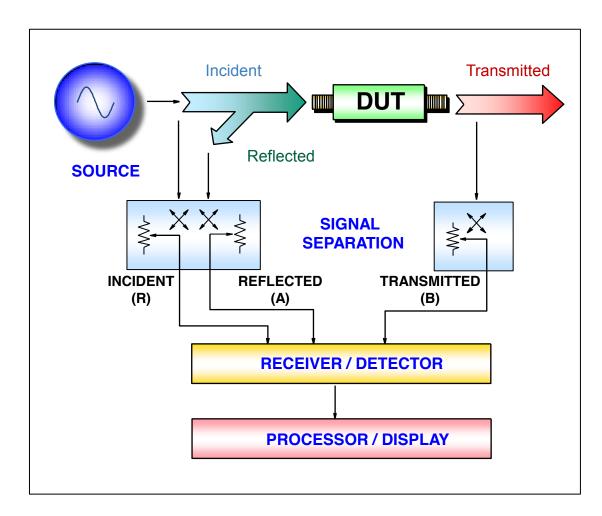
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VNA Building Blocks

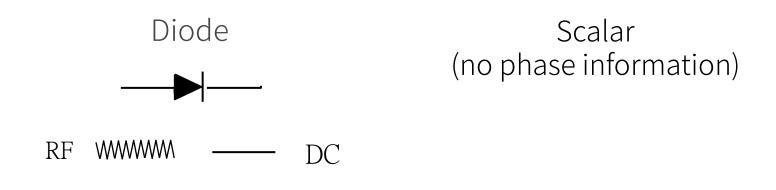


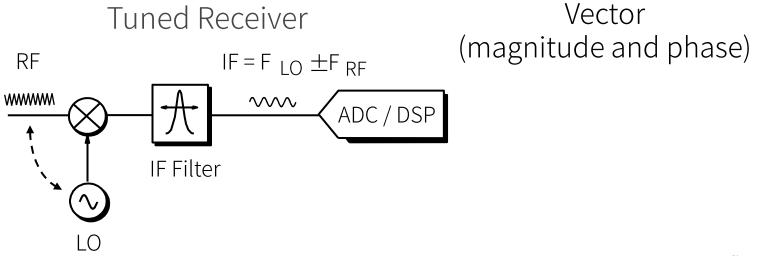
Picture source: D. Ballo Keysight

MPI



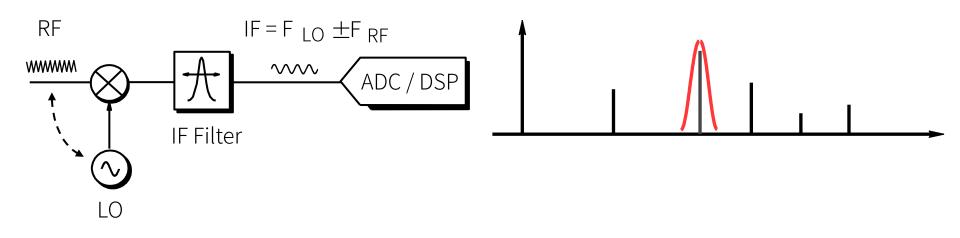
Receiver / Detectors







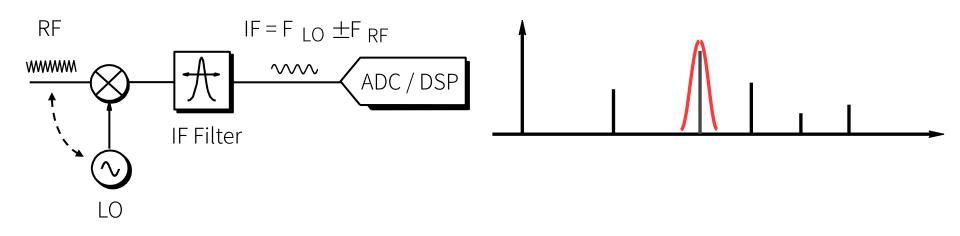
Narrowband Detection: Heterodyne Receiver



- Best sensitivity / dynamic range
- Provides harmonic / spurious signal rejection



Narrowband Detection: Heterodyne Receiver



Trade off: noise floor and measurement speed

IF Bandwidth and Averaging

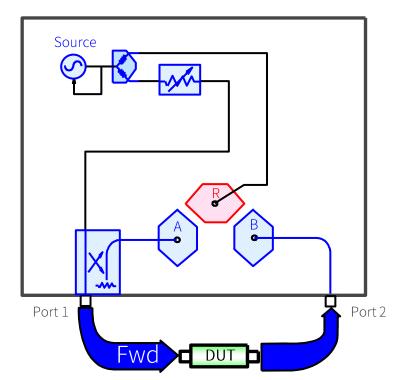
- Improve dynamic range by:
 - increasing power,
 - decreasing IF bandwidth, or
 - Averaging

IF Bandwidt	h	×				
IF Bandwidth						
Reduce IF BW at Low Frequencies						
OK	Cancel	Help				

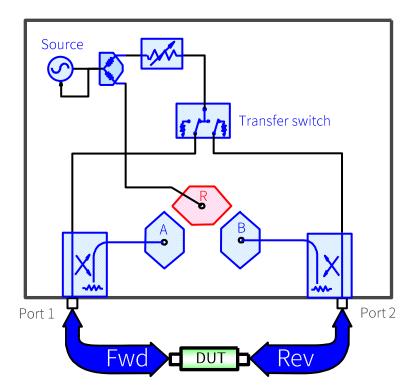
- Recommended IFBW value 100 Hz
- Averaging: OFF

T/R Versus S-Parameter Test Sets

Transmission/Reflection Test Set



RF always comes out port 1 Port 2 is always receiver Response, one-port cal available S-Parameter Test Set

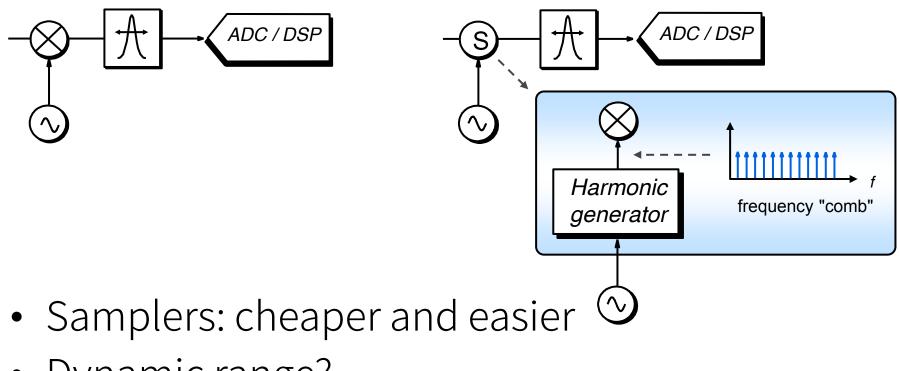


RF comes out port 1 or port 2 Forward and reverse measurements Two-port calibration possible

Front Ends: Mixers Versus Samplers

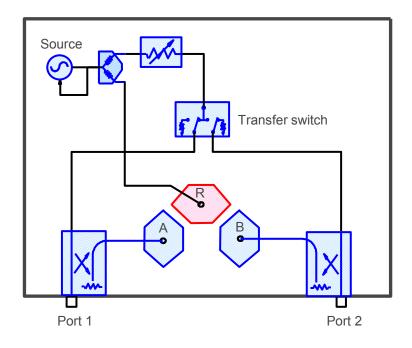
Mixer-based front end

Sampler-based front end

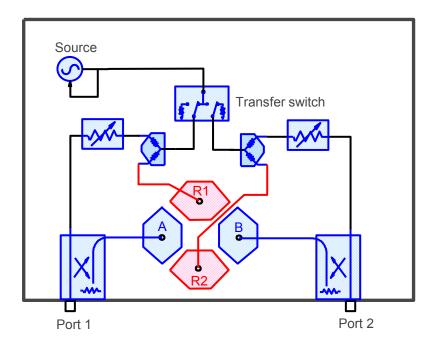


• Dynamic range?

Three vs. Four-Receiver Analyzers



Reference Channel
 – Economy
 – Up to 20 GHz



Double-Reflectometer
 – High-end
 – Up to THz



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What do we have today?

Instruments



/INCITSU envision : ensure







Frequency Extenders





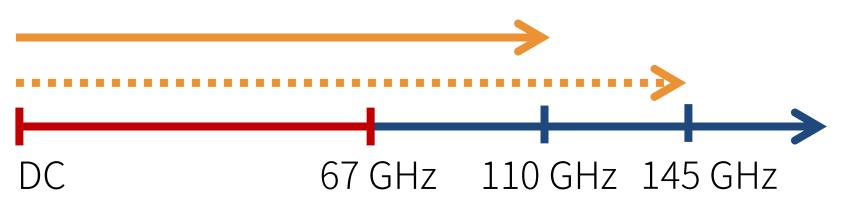




Frequency Range

- Baseband unit

 From few Hz to 67 GHz
- Frequency extenders
 - From 67 GHz to 1.1 THz
 - Single sweep: from DC to 110 GHz (145 GHz)



Keysight (former Agilent)





PNA-X

FiledFox PXI-VNA

ENA

PNA Family

	Model		Typical application	Frequency range
- PNA Family Reach for unrivaled excellence		N524xA PNA-X Series Most advanced and flexible VNA	 Replace an entire rack of equipment with one instrument Complete linear and nonlinear active device characterization 	 10 MHz to 8.5/13.5/26.5/ 43.5/50/67 GHz Up to 1.1 THz with extenders
		N522xA PNA Series High performance microwave VNA	 Highest performance passive component analysis Active components characterization Metrology and cal lab 	 10 MHz to 13.5/26.5/ 43.5/50/67 GHz Up to 1.1 THz with extenders
		N523xA PNA-L Series Economy microwave VNA	 Microwave S-parameter test Signal integrity Material measurements 	 300 kHz to 8.5/13.5/20 GHz 10 MHz to 43.5/50 GHz

ENA Family

	Model		Typical application	Frequency range
ENA Drive down the cost of test		E5072A ENA High performance RF VNA with configurable test set	 RF amplifier test BTS components PIM measurements 	 30 kHz to 4.5/8.5 GHz
		E5071C ENA High performance RF VNA	 RF component test Multiport module test Material measurements Signal integrity 	 9 kHz to 4.5/6.5/8.5 GHz 300 kHz to 14/20 GHz
		E5061B ENA LF-RF VNA with impedance analysis function Low cost RF VNA	 LF component/circuit test Component Z evaluation RF component test CATV component test 	 5 Hz to 3 GHz 100 kHz to 1.5/3 GHz
		E5063A ENA Low-cost RF VNA for passive component test	 Antenna manufacturing test RF passive component test Material measurements PCB manufacturing test 	 100 kHz to 4.5/8.5/18 GHz







Midrange: ZVB 40GHz



Economy: ZVD 8.5GHz



Portable: ZVL 13.5GHz

Incitsu envision : ensure



VectorStar: ME7838



ShockLine: MS46xxx 40GHz



New Players



S5048 4.8GHz





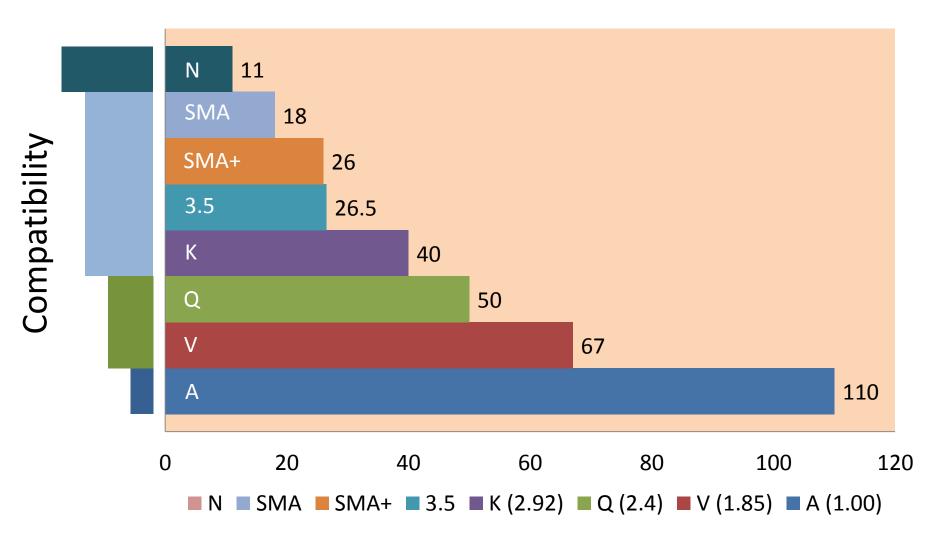






PXIe-5632. 8.5GHz

Frequency Limits and Compatibility





Cable and Connectors



SMA

K (2.92 mm)

Q (2.4 mm)

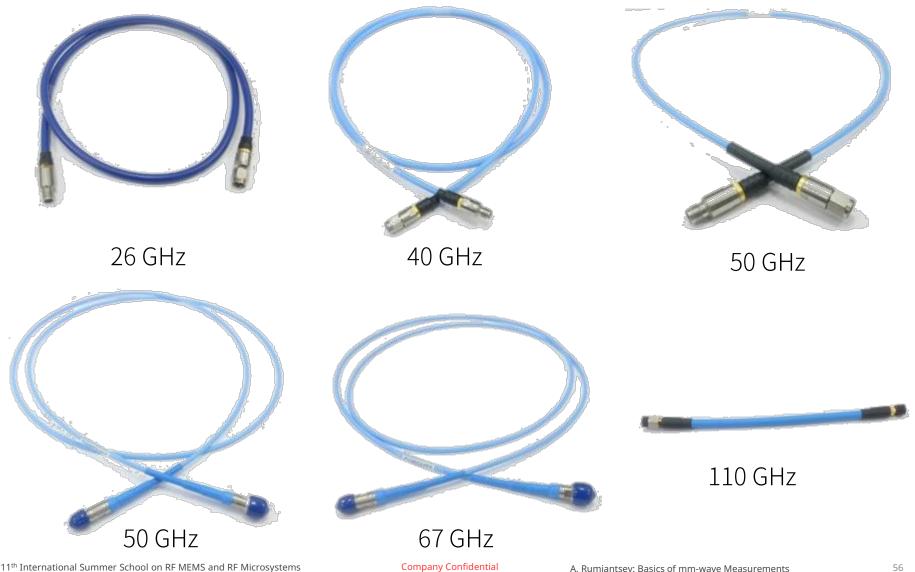


V (1.85 mm)



A (1.00 m)

Cables

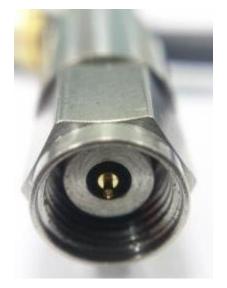


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Comparison







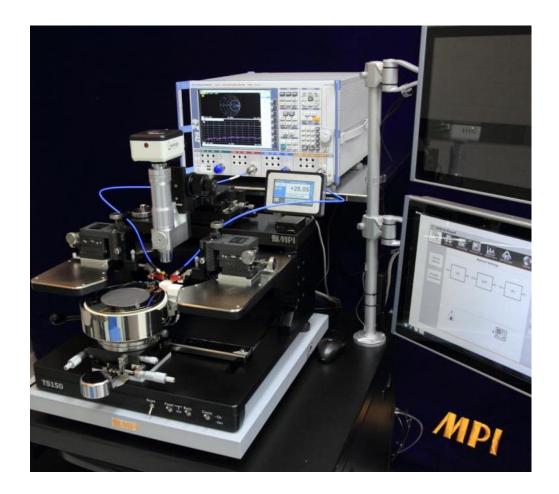


High-end



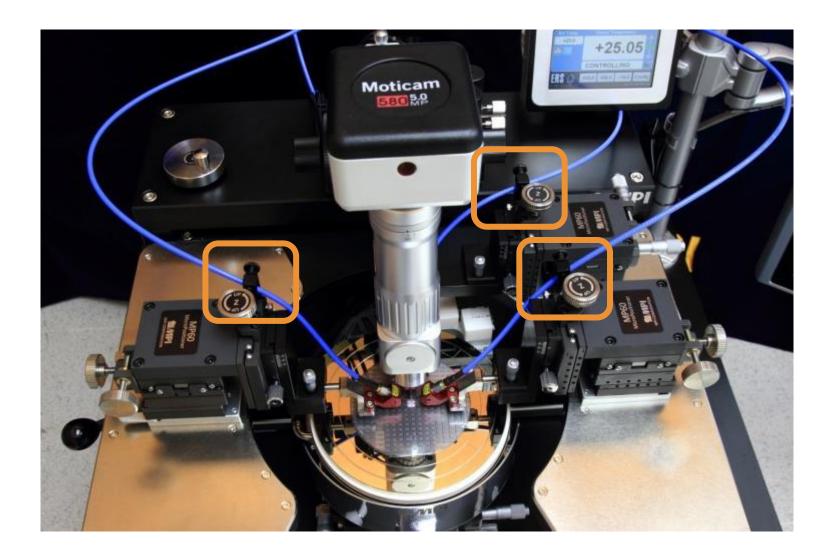
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VNA Integration



- At the back
- Integrated shelf
- Optimized cable length: 80 cm

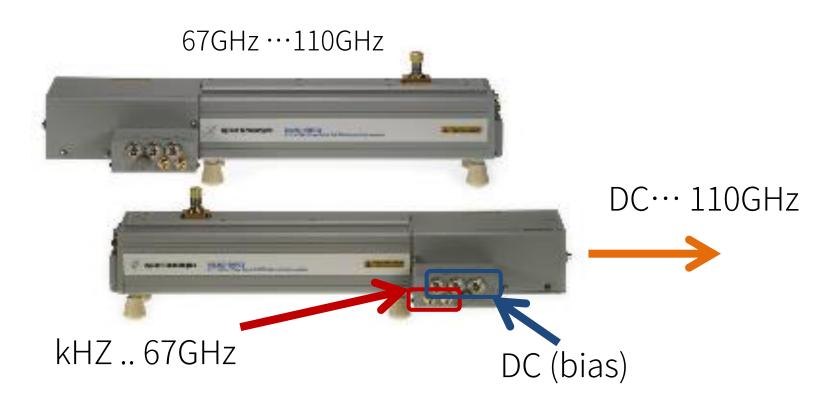
Cable Management on Positioner



Beyond 67 GHz below 110 GHz

- External mm-wave heads ("extenders")
 From 67 GHz to 110 GHz
- Combiners
 - DC (bias source)
 - kHz…67GHz (baseband VNA)
 - 67GHz..110GHz (extenders)
- Broadband S-parameter measurement system

mm-Wave Heads



- IV/ S-Parameters measurements
- Device characterization for modeling

with Option H11 N5250A system block diagram Test set I/O OOE Π Receiver A Receiver B 60 00 Port 2 🎯 Port 1 -0 0 0 0-30 in, 76.2 cm 30 in. 76.2 cm LO RF IF1 IF3 IF2 IF4 48 in. 48 in. 121.9 cm 121.9 cm Test set controller N5260A with Optional bias-tees test heads (Option 017) Test 67 to 110 GHz Test 67 to 110 GHz port 1 port 2 waveguide head waveguide head Combiner assembly

E8361A

Combiner assembly

Picture source: Keysight



Broadband Systems



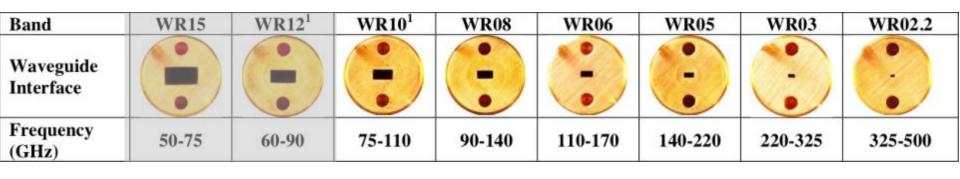
Key Wafer-Level Requirement

• mm-wave heads close to the DUT





Banded Solutions



• Dedicated mm-wave extender per band

• Our interest: from WR-10 and beyond

Banded Solutions: up to 1.1THz









Banded Solutions: up to 500GHz







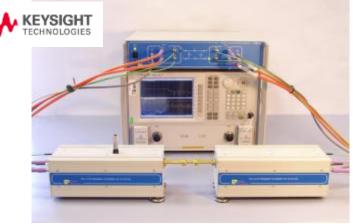
Banded Solutions: up to 500 GHz

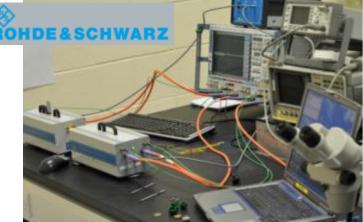


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Banded Solutions: up to 325 GHz

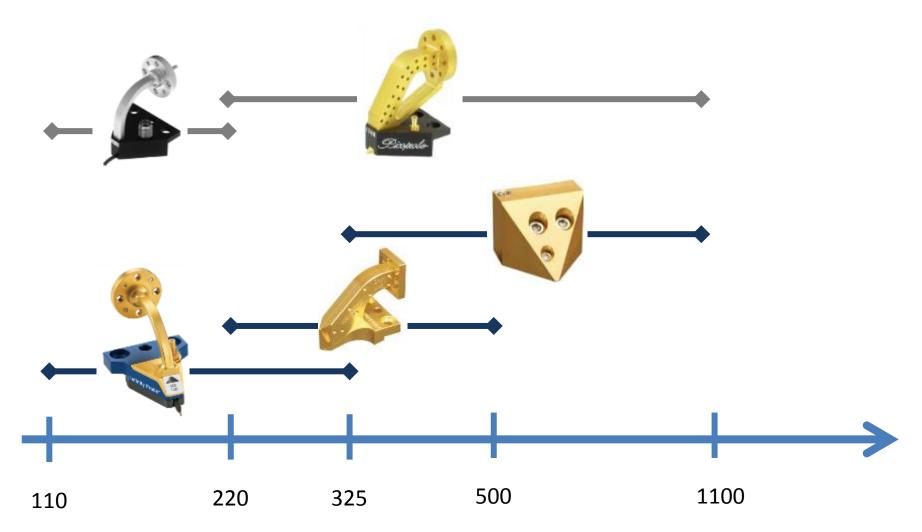








Banded Probes



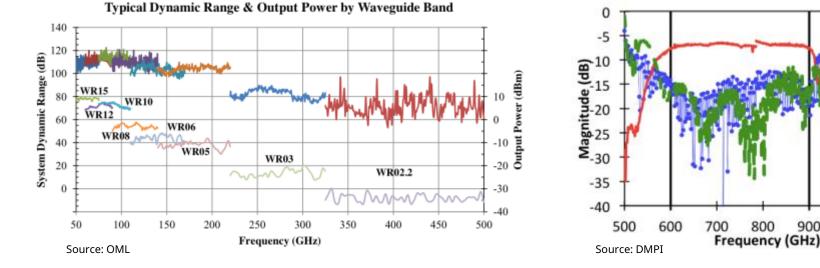
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- Waveguide losses increases

OML's VNA Frequency Extension Modules

• Probe performance degrades





DMPI 1.1 THz Probe

900

A. Rumiantsev: Basics of mm-wave Measurements

1000

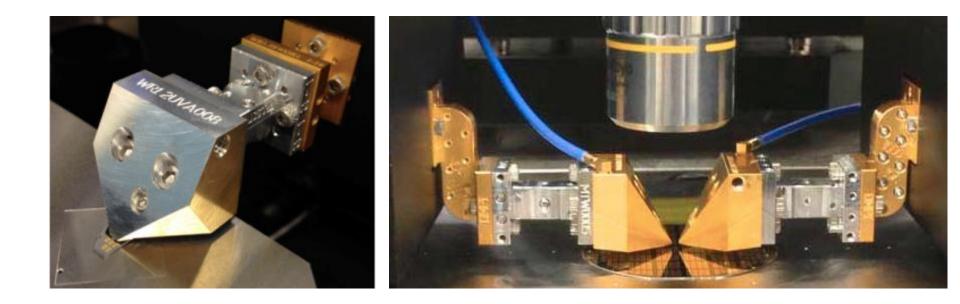
1100

MPI

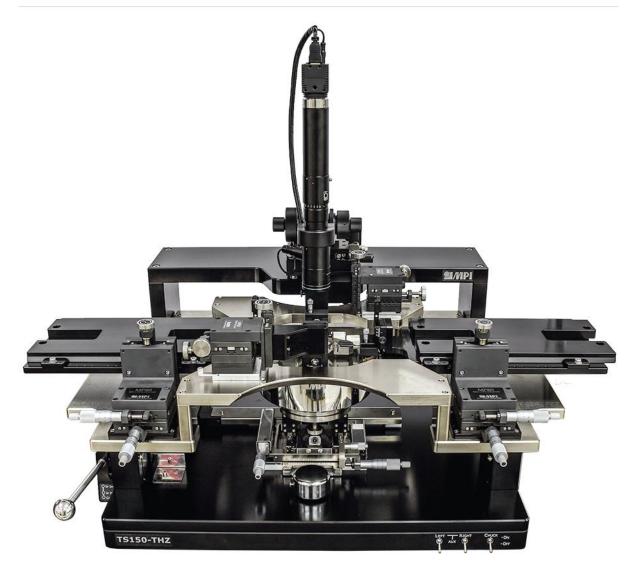
Banded Measurement Challenges



Probe Integration



Dedicated TS150-THZ System



: Ready for "The Test"



MPI TS150-THZ | 150 mm Manual Probe System

The first ever, explicit designed probe system for accurate mmW and THz measurements

Microscope Mount and Movement

- Stable bridge for high quality optics
- · 90° tilt for easy reconfiguration
- 50 x 50 mm linear XY movement

4-Port Bridge

- · Two: in North and South
- Rectangular adjustments for RF positioners
- · Designed as standard feature for DC biasing or 4-port RF
- For single DC or RF MicroPositioners

MicroPositioners

- Supports max. two, bold down large area MP80 MicroPositioners
- · Unique over-travel control option
- MP80-DX option for accurate multi-line TRL calibration

Probe Platen

- Single large probe platen in rigid design
- 4 probe platen supports for max. stability
- Designed especially to accomodate large positioners for mmW and THz applications

Unique Platen Lift

- Three discrete positions for contact, separation (300 µm) and safety loading 3 mm
- · Safety lock function at loading position
- "Automated" contact position with ±1 µm repeatability for consistent contact quality

Small Footprint

- Designed for bench top use
- Comes with vibration absorber base
- · Low profile design for maximum usability
- Ideal for mmW, THz and load pull applications

Front Mounted Vacuum Control

- Easy access
- Clearly marked



TS150-THZ

Available Options

말만날

Various adaptations for different
 Fable with integrated rack for thermal controller,
 frequency extenders
 Object of the standard option
 Instrument shelf option

Microscope and Optics Options

- Various optics options available
- Single tube MPI SZ10, MZ12 with up to 12x zoom and 95 mm working distance
- · HDMI cameras with up to 5 MP available

Modular Chucks

- Ambient or hot only chucks
- · Dedicated RF or mmW designs
- · Field upgradable for reduced cost of ownership
- · Easy switch between center and small wafer size control

RF Calibration

- 2 auxiliary chucks for calibration substrates
- · Built-in ceramic for accurate calibration
- 1 µm flatness for consistent contact quality

MP80 Integration Modules

- 2 options for waveguide or coax application
- Universal large area platforms for integrating various frequency extenders up to 1.1 THz
- Unique air-spring design for balance weight compensation and max. stability
- Micrometer screws for fine waveguide probe leveling on the platforms
- Dove-tail interface for dedicated adaptations for easy setup and switching between different frequency bands

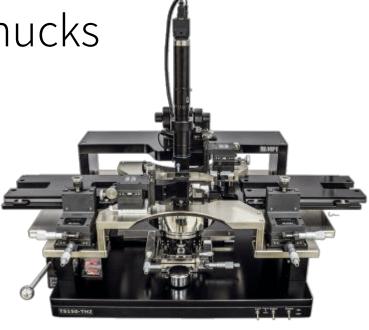
Chuck XYZ Stage Movement

- Unique puck control air bearing stage for quick onehand operation
- · Large vacuum base for max. stability
- 175 x 225 mm XY fast movement
- 25 x 25 mm micrometer fine XY adjustment
- 10 mm fine Z chuck adjustment
- ±5° Theta fine adjustment
- Extra wide Y-range for easy loading

Designed for unsurpassed stability

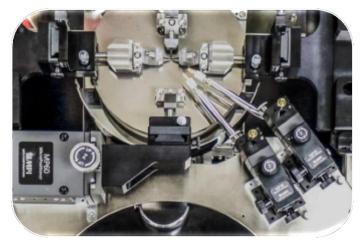
- Large area stainless steel probe platen
- Probe platen at lowest possible position
- No chuck elevation
- Ceramic chuck and AUX chucks

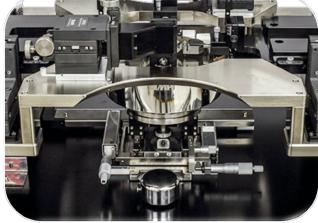




Dedicated Design for THz Application

- Support R&S and all other extenders:
 up to 1.1THz
- 4-Port as part of the base system
- Fine Z chuck











THANK YOU FOR YOUR ATTENTION

For more information, please visit: www.mpi-corporation.com